



1490nm Pulse Laser For OTDR

Features

- High output power $P_f = 40\sim 60$ mW @ IFP = 400mA
- Long wavelength $\lambda_c = 1490$ nm
- Built-in monitor PD
- Pulse Conditions: Pulse width (PW) = 10 μ s, Duty = 1%



Applications

OTDR System

Absolute Maximum Ratings

Parameter	Symbol	Min.	Typical.	Max.	Unit
Pulsed Forward Current	IFP			750	mA
Reverse Voltage	VR			2	V
Reverse Voltage (monitor PD)	VRM			10	V
Reverse Current (monitor PD)	IFPM			2	mA
Operating Case Temperature	TC	0		60	°C
Storage Temperature	Tstg	-40		85	°C
Lead Soldering Temperature	Tsld			260(10s)	°C
Relative Humidity (noncondensing)	RH			85	%

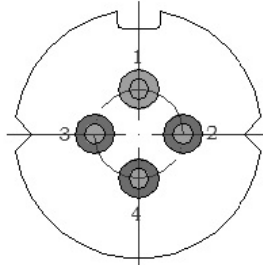
Optical & Electrical Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Notes
Forward Voltage	VFP			3.5	V	IFP = 400 mA, PW = 10 μ s, Duty = 1%
Threshold Current	I _{th}		20	35	mA	
Optical Output Power From Fiber	P _f	40	60		mW	IFP = 400 mA, PW = 10 μ s, Duty = 1%
Center Wavelength	λ_c	1470	1490	1510	nm	IFP = 400 mA, PW = 10 μ s, Duty = 1%
Spectral Width	σ			4	nm	RMS (-3 dB)
Rise Time	t _r		0.5	2.0	ns	10-90%
Fall Time	t _f		0.5	2.0	ns	90-10%
Monitor Current	I _m	0.05		2	mA	VRM = 5V



Pin Description:

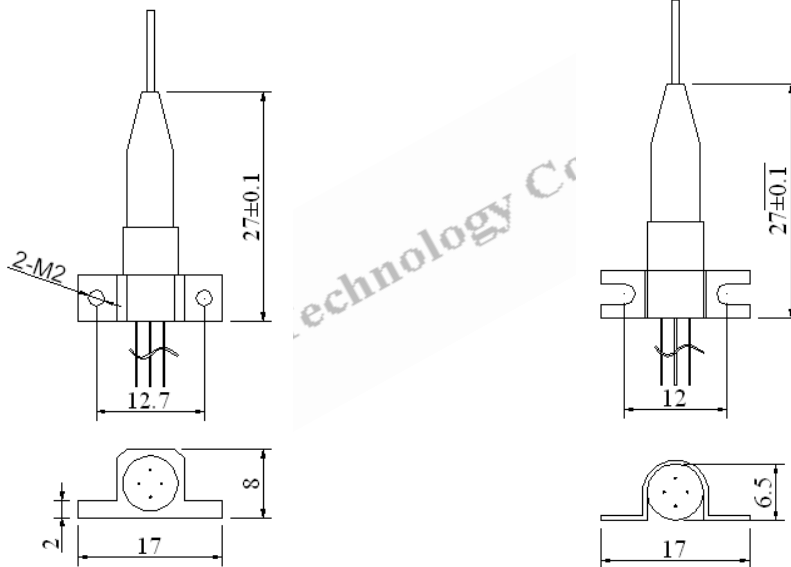
LD:



Type A:

- 【1】 LD +
- 【2】 LD -
- 【3】 PD +
- 【4】 PD -

Package Outline



Order Information

PLD-F492-XAXX

P	LD	-F	49	2	-X	A	X	X
Mode	Product Type	Chip	Wavelength	Bandwidth	Connector	Pin	Pigtail Length	Power Range
		F: FP	49: 1490nm	2: 2.5Gb/s	1: FC/APC 2: FC/PC 3: SC/APC 4: SC/PC 5: LC/PC 6: LC/APC	A: 725	05: 0.5m 10: 1.0m	P40: >40mW P60: >60mW

Additional requirements can be settled through friendly negotiation.

Shengshi Optical Tech. Co.,Ltd reserves the right to make changes to the product or information contained herein without notice.